THE DATASHEET OF

TPS77018DBVT

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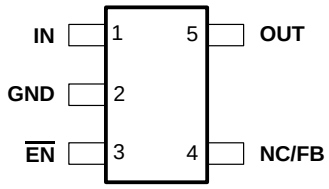
ULTRALOW-POWER 50-mA LOW-DROPOUT LINEAR REGULATORS

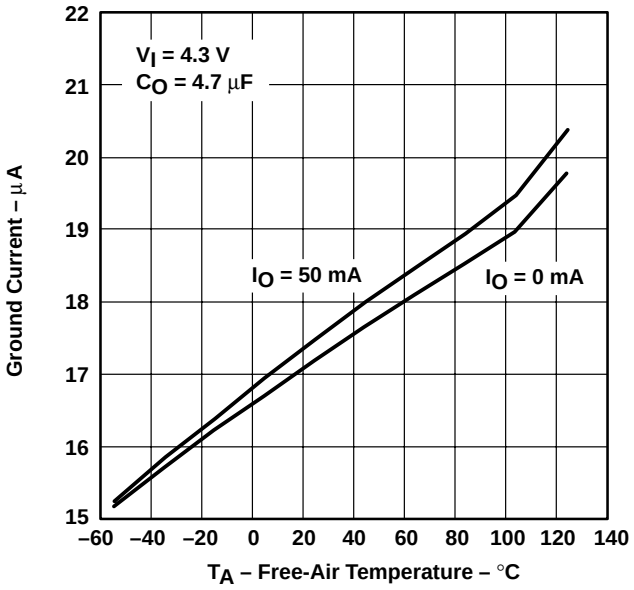
SLVS210D – JUNE 1999 – REVISED MAY 2001

- **50-mA Low-Dropout Regulator**
- **Available in 1.2-V, 1.5-V, 1.8-V, 2.5-V, 2.7-V, 2.8-V, 3.0-V, 3.3-V, and 5-V Fixed-Output and Adjustable Versions**
- **Only 17 μA Quiescent Current at 50 mA**
- **1 μA Quiescent Current in Standby Mode**
- **Dropout Voltage Typically 35 mV at 50 mA**
- **Over Current Limitation**
- **–40°C to 125°C Operating Junction Temperature Range**
- **5-Pin SOT-23 (DBV) Package**

DBV PACKAGE
(TOP VIEW)



TPS77033
GROUND CURRENT
vs
FREE-AIR TEMPERATURE



description

The TPS770xx family of low-dropout (LDO) voltage regulators offers the benefits of low dropout voltage, ultralow-power operation, and miniaturized packaging. These regulators feature low dropout voltages and ultralow quiescent current compared to conventional LDO regulators. Offered in a 5-terminal small outline integrated-circuit SOT-23 package, the TPS770xx series devices are ideal for micropower operations and where board space is at a premium.

A combination of new circuit design and process innovation has enabled the usual PNP pass transistor to be replaced by a PMOS pass element. Because the PMOS pass element behaves as a low-value resistor, the dropout voltage is very low — typically 35 mV at 50 mA of load current (TPS77050) — and is directly proportional to the load current. Since the PMOS pass element is a voltage-driven device, the quiescent current is ultralow (28 μA maximum) and is stable over the entire range of output load current (0 mA to 50 mA). Intended for use in portable systems such as laptops and cellular phones, the ultralow-dropout voltage feature and ultralow-power operation result in a significant increase in system battery operating life.

The TPS770xx also features a logic-enabled sleep mode to shut down the regulator, reducing quiescent current to 1 μA typical at T_J = 25°C. The TPS770xx is offered in 1.2-V, 1.5-V, 1.8-V, 2.5-V, 2.7-V, 2.8-V, 3.0-V, 3.3-V, and 5-V fixed-voltage versions and in a variable version (programmable over the range of 1.2 V to 5.5 V).

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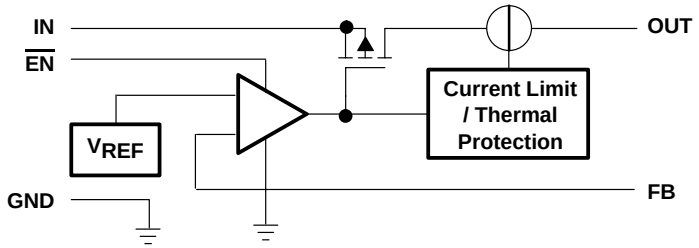
AVAILABLE OPTIONS

T_J	VOLTAGE	PACKAGE	PART NUMBER		SYMBOL
–40°C to 125°C	Variable 1.2V to 5.5V	SOT-23 (DBV)	TPS77001DBVT†	TPS77001DBVR‡	PCPI
	1.2 V		TPS77012DBVT†	TPS77012DBVR‡	PCQI
	1.5 V		TPS77015DBVT†	TPS77015DBVR‡	PCRI
	1.8 V		TPS77018DBVT†	TPS77018DBVR‡	PCSI
	2.5 V		TPS77025DBVT†	TPS77025DBVR‡	PCTI
	2.7 V		TPS77027DBVT†	TPS77027DBVR‡	PCUI
	2.8 V		TPS77028DBVT†	TPS77028DBVR‡	PCVI
	3.0 V		TPS77030DBVT†	TPS77030DBVR‡	PCWI
	3.3 V		TPS77033DBVT†	TPS77033DBVR‡	PCXI
	5.0 V		TPS77050DBVT†	TPS77050DBVR‡	PCYI

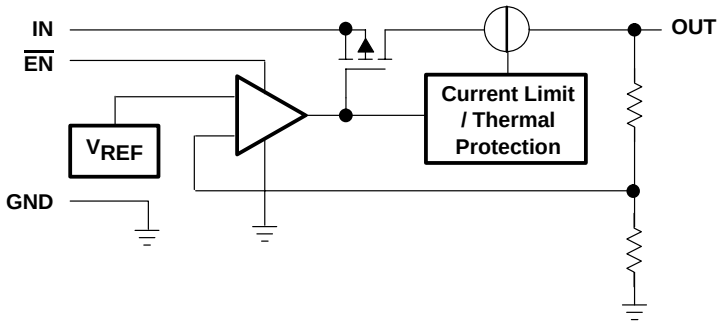
† The DBVT indicates tape and reel of 250 parts.
‡ The DBVR indicates tape and reel of 3000 parts.

functional block diagram

TPS77001



TPS77012/15/18/25/27/28/30/33/50



Terminal Functions

TERMINAL NAME	TERMINAL NO.	I/O	DESCRIPTION
GND	2		Ground
$\overline{EN}$	3	I	Enable input
FB	4	I	Feedback voltage (TPS77001 only)
IN	1	I	Input supply voltage
NC	4		No connection (Fixed options only)
OUT	5	O	Regulated output voltage

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Input voltage range (see Note 1) . . . . . –0.3 V to 13.5 V
Voltage range at $\overline{EN}$ . . . . . –0.3 V to V_I + 0.3 V
Voltage on OUT, FB . . . . . 7 V
Peak output current . . . . . Internally limited
ESD rating, HBM . . . . . 2 kV
Continuous total power dissipation . . . . . See Dissipation Rating Table
Operating virtual junction temperature range, T_J . . . . . –40°C to 150°C
Storage temperature range, T_{stg} . . . . . –65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to network ground terminal.

DISSIPATION RATING TABLE

BOARD	PACKAGE	$R_{\theta JC}$	$R_{\theta JA}$	DERATING FACTOR ABOVE T_A = 25°C	$T_A \le 25°C$ POWER RATING	T_A = 70°C POWER RATING	T_A = 85°C POWER RATING
Low K‡	DBV	65.8 °C/W	259 °C/W	3.9 mW/°C	386 mW	212 mW	154 mW
High K§	DBV	65.8 °C/W	180 °C/W	5.6 mW/°C	555 mW	305 mW	222 mW

‡ The JEDEC Low K (1s) board design used to derive this data was a 3 inch x 3 inch, two layer board with 2 ounce copper traces on top of the board.
§ The JEDEC High K (2s2p) board design used to derive this data was a 3 inch x 3 inch, multilayer board with 1 ounce internal power and ground planes and 2 ounce copper traces on top and bottom of the board.

recommended operating conditions

	MIN	NOM	MAX	UNIT
Input voltage, V_I (see Note 2)	2.7		10	V
Output voltage range, V_O	1.2		5.5	V
Continuous output current, I_O (see Note 3)	0		50	mA
Operating junction temperature, T_J	–40		125	°C

NOTES: 2. To calculate the minimum input voltage for your maximum output current, use the following formula:
$V_I(min) = V_O(max) + V_{DO}$ (max load)
3. Continuous output current and operating junction temperature are limited by internal protection circuitry, but it is not recommended that the device operate under conditions beyond those specified in this table for extended periods of time.

electrical characteristics over recommended operating free–air temperature range, $V_I = V_{O(typ)} + 1$ V, $I_O = 50$ mA, $\overline{EN} = 0$V, $C_o = 4.7$ μF (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
Output voltage (10 μA to 50 mA load) (see Note 4)	TPS77001	1.2 V ≤ V_O ≤ 5.5 V,	T_J = 25°C		V_O		V
		1.2 V ≤ V_O ≤ 5.5 V,	T_J = –40°C to 125°C	0.97V_O		1.03V_O	
	TPS77012	T_J = 25°C,	2.7 V < V_{IN} < 10 V		1.224		
		T_J = –40°C to 125°C,	2.7 V < V_{IN} < 10 V	1.187		1.261	
	TPS77015	T_J = 25°C,	2.7 V < V_{IN} < 10 V		1.5		
		T_J = –40°C to 125°C,	2.7 V < V_{IN} < 10 V	1.455		1.545	
	TPS77018	T_J = 25°C,	2.8 V < V_{IN} < 10 V		1.8		
		T_J = –40°C to 125°C,	2.8 V < V_{IN} < 10 V	1.746		1.854	
	TPS77025	T_J = 25°C,	3.5 V < V_{IN} < 10 V		2.5		
		T_J = –40°C to 125°C,	3.5 V < V_{IN} < 10 V	2.425		2.575	
	TPS77027	T_J = 25°C,	3.7 V < V_{IN} < 10 V		2.7		
		T_J = –40°C to 125°C,	3.7 V < V_{IN} < 10 V	2.619		2.781	
	TPS77028	T_J = 25°C,	3.8 V < V_{IN} < 10 V		2.8		
		T_J = –40°C to 125°C,	3.8 V < V_{IN} < 10 V	2.716		2.884	
	TPS77030	T_J = 25°C,	4.0 V < V_{IN} < 10 V		3.0		
		T_J = –40°C to 125°C,	4.0 V < V_{IN} < 10 V	2.910		3.090	
	TPS77033	T_J = 25°C,	4.3 V < V_{IN} < 10 V		3.3		
		T_J = –40°C to 125°C,	4.3 V < V_{IN} < 10 V	3.201		3.399	
	TPS77050	T_J = 25°C,	6.0 V < V_{IN} < 10 V		5.0		
		T_J = –40°C to 125°C,	6.0 V < V_{IN} < 10 V	4.850		5.150	
Quiescent current (GND current) (see Note 4)		$\overline{EN}$ = 0V, T_J = 25°C	0 mA < I_O < 50mA,		17		μA
		$\overline{EN}$ = 0V, T_J = –40°C to 125°C	I_O = 50mA,			28	
Output voltage line regulation ($\Delta V_O/V_O$) (see Notes 4 and 5)		V_O + 1 V < V_I ≤ 10 V,	T_J = 25°C		0.04		%/V
		V_O + 1 V < V_I ≤ 10 V, T_J = –40°C to 125°C				0.1	
Load regulation		$\overline{EN}$ = 0V, T_J = 25°C	I_O = 0 to 50 mA,		8		mV
Output noise voltage		BW = 300 Hz to 50 kHz, C_o = 10 μF,	T_J = 25°C		190		μVrms
Output current limit		V_O = 0V,	See Note 4		350	750	mA
Standby current		$\overline{EN}$ = V_I,	2.7 < V_I < 10 V		1		μA
		T_J = –40°C to 125°C				2	μA

NOTES: 4. Minimum IN operating voltage is 2.7 V or V_O (typ) + 1 V, whichever is greater. Maximum IN voltage 10 V, minimum output current 10 μA, maximum output current 50 mA.

5. If $V_O \le 1.8$ V then $V_{Imin} = 2.7$ V, $V_{Imax} = 10$ V:

$$\text{Line Reg. (mV)} = (\%/V) \times \frac{V_O\left(V_{Imax} - 2.7\ V\right)}{100} \times 1000$$

If $V_O \ge 2.5$ V then $V_{Imin} = V_O + 1$ V, $V_{Imax} = 10$ V:

$$\text{Line Reg. (mV)} = (\%/V) \times \frac{V_O\left(V_{Imax} - \left(V_O + 1\ V\right)\right)}{100} \times 1000$$

electrical characteristics over recommended operating free–air temperature range, $V_I = V_{O(typ)} + 1$ V, $I_O = 50$ mA, $\overline{EN} = 0$V, $C_o = 4.7$ μF (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
FB input current		FB = 1.224 V (TPS77001)		–1		1	μA
High level enable input voltage		2.7 V < V_I < 10 V		1.7			V
Low level enable input voltage		2.7 V < V_I < 10 V				0.9	V
Power supply ripple rejection		f = 1 kHz, T_J = 25°C,	C_O = 10 μF, See Note 4		60		dB
Input current (EN)		$\overline{EN}$ = 0 V		–1	0	1	μA
		$\overline{EN}$ = V_I		–1		1	μA
Dropout voltage (see Note 6)	TPS77028	I_O = 50 mA,	T_J = 25°C		60		mV
		I_O = 50 mA	T_J = –40°C to 125°C			125	
	TPS77030	I_O = 50 mA,	T_J = 25°C		57		
		I_O = 50 mA	T_J = –40°C to 125°C			115	
	TPS77033	I_O = 50 mA,	T_J = 25°C		48		
		I_O = 50 mA	T_J = –40°C to 125°C			100	
	TPS77050	I_O = 50 mA,	T_J = 25°C		35		
		I_O = 50 mA	T_J = –40°C to 125°C			85	

NOTES: 4. Minimum IN operating voltage is 2.7 V or V_O (typ) + 1 V, whichever is greater. Maximum IN voltage 10 V, minimum output current 10 μA, maximum output current 50 mA.

6. IN voltage equals V_O(Typ) –100mV; TPS77001 output voltage set to 3.3 V nominal with external resistor divider. TPS77012, TPS77015, TPS77018, TPS77025, and TPS77027 dropout voltage limited by input voltage range limitations.

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_O	Output voltage	vs Output current	1, 2, 3
		vs Free-air temperature	4, 5, 6
	Ground current	vs Free-air temperature	7
	Output spectral noise density	vs Frequency	8
Z_o	Output impedance	vs Frequency	9
V_{DO}	Dropout voltage	vs Free-air temperature	10
	Ripple rejection	vs Frequency	11
	LDO startup time		12
	Line transient response		13, 15
	Load transient response		14, 16
	Equivalent series resistance (ESR)	vs Output current	17, 19
		vs Added ceramic capacitance	18, 20

TYPICAL CHARACTERISTICS

TPS77025
OUTPUT VOLTAGE vs OUTPUT CURRENT

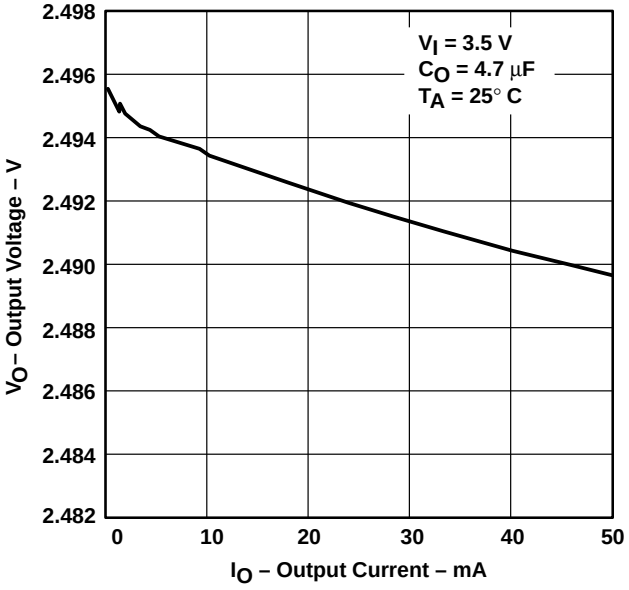


Figure 1

TPS77015
OUTPUT VOLTAGE vs OUTPUT CURRENT

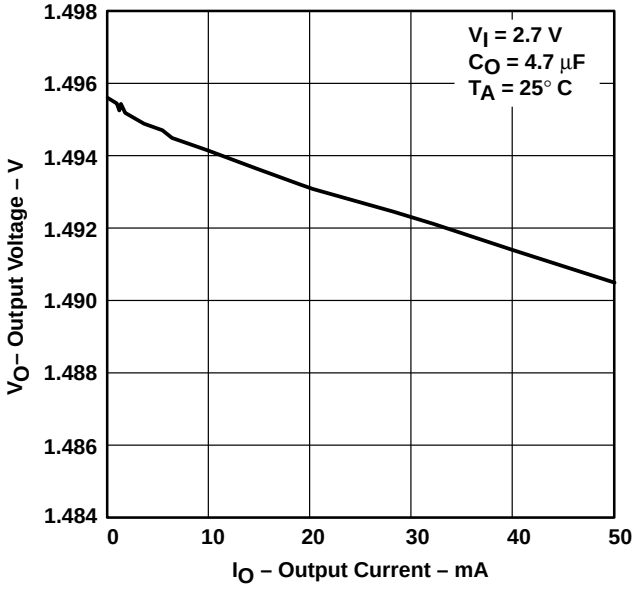


Figure 2

TPS77033
OUTPUT VOLTAGE vs OUTPUT CURRENT

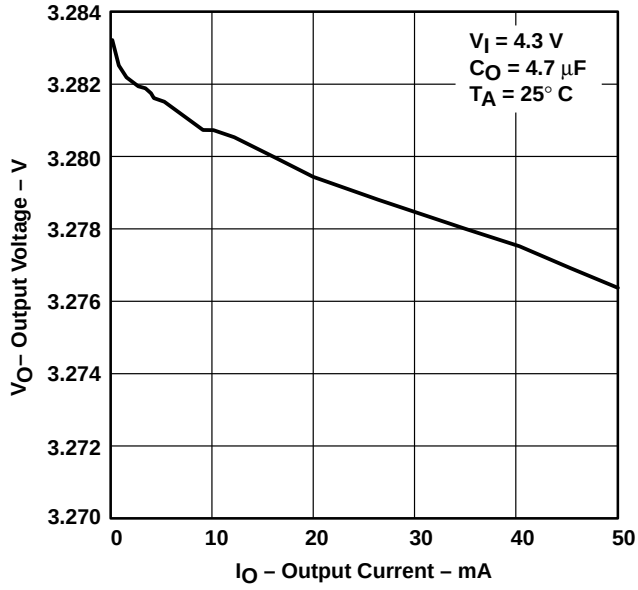


Figure 3

TPS77015
OUTPUT VOLTAGE vs FREE-AIR TEMPERATURE

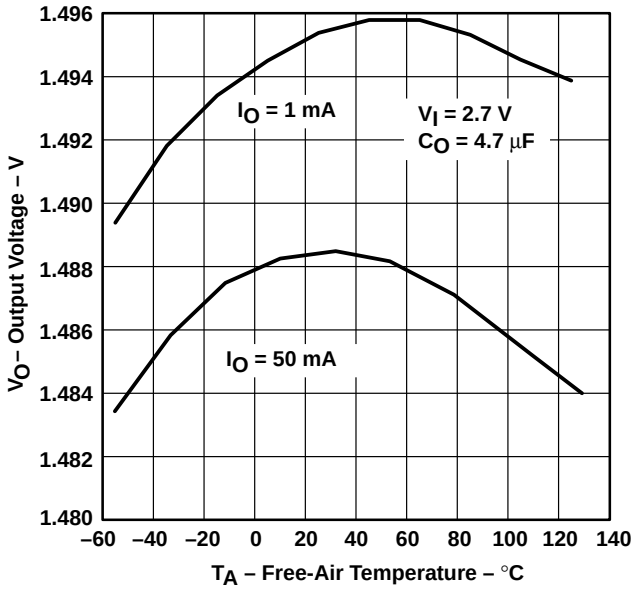


Figure 4

TYPICAL CHARACTERISTICS

TPS77025
OUTPUT VOLTAGE
vs
FREE-AIR TEMPERATURE

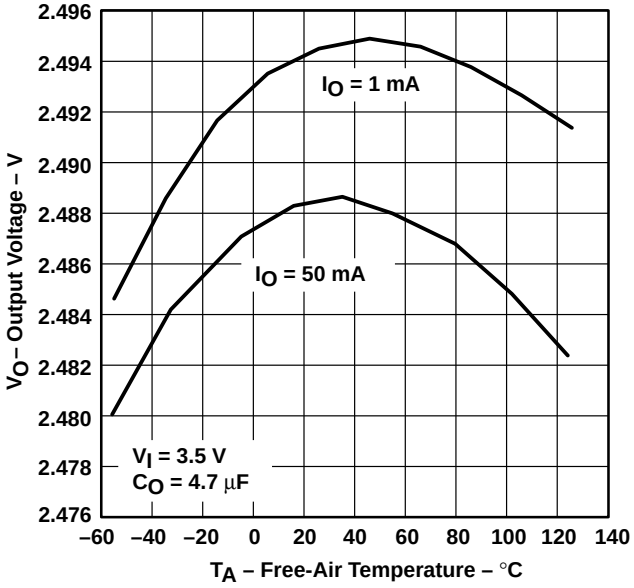


Figure 5

TPS77033
OUTPUT VOLTAGE
vs
FREE-AIR TEMPERATURE

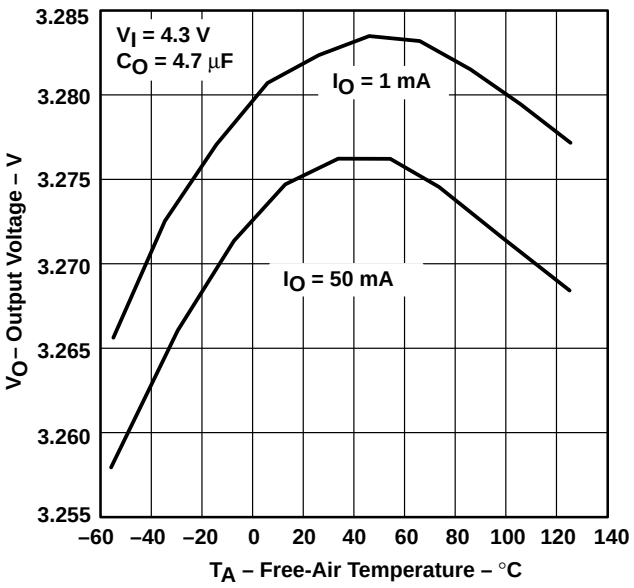


Figure 6

TPS77033
GROUND CURRENT
vs
FREE-AIR TEMPERATURE

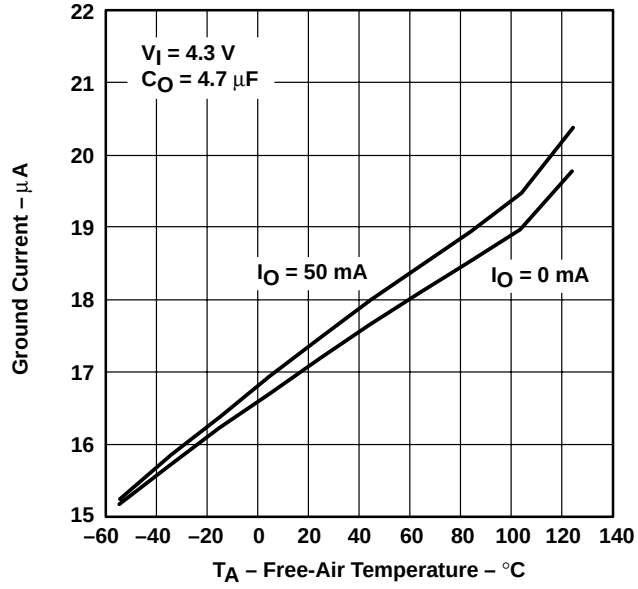


Figure 7

TPS77033
OUTPUT SPECTRAL NOISE DENSITY
vs
FREQUENCY

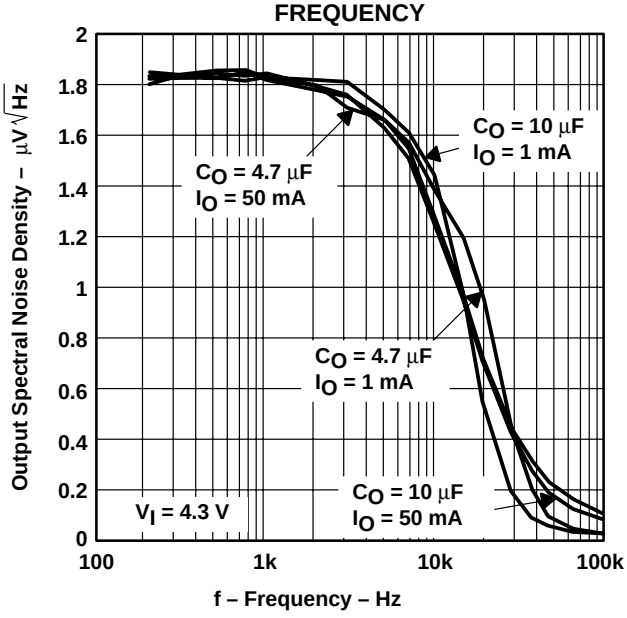


Figure 8

TYPICAL CHARACTERISTICS

OUTPUT IMPEDANCE vs FREQUENCY

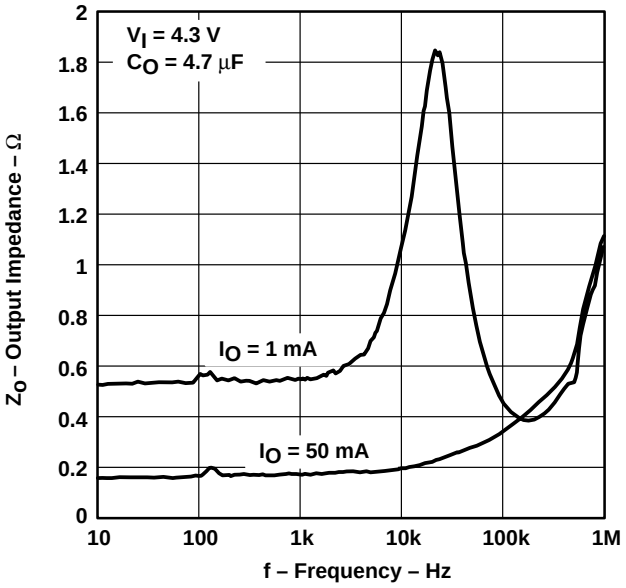


Figure 9

TPS77033
DROPOUT VOLTAGE vs FREE-AIR TEMPERATURE

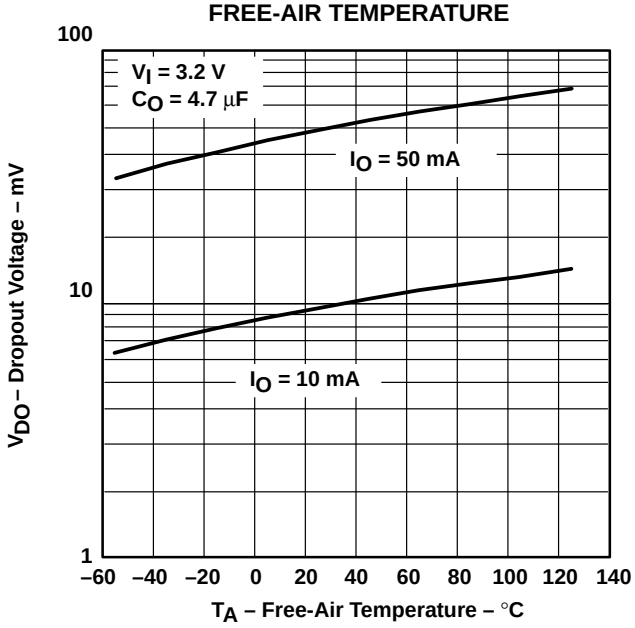


Figure 10

TPS77033
RIPPLE REJECTION vs FREQUENCY

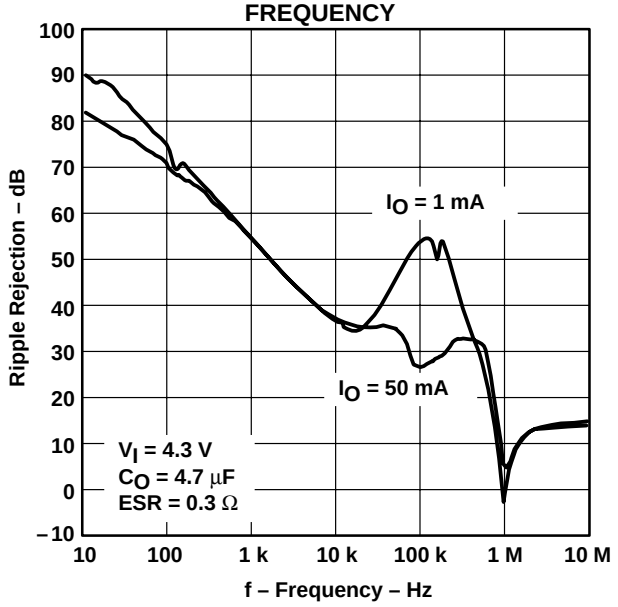


Figure 11

LDO STARTUP TIME

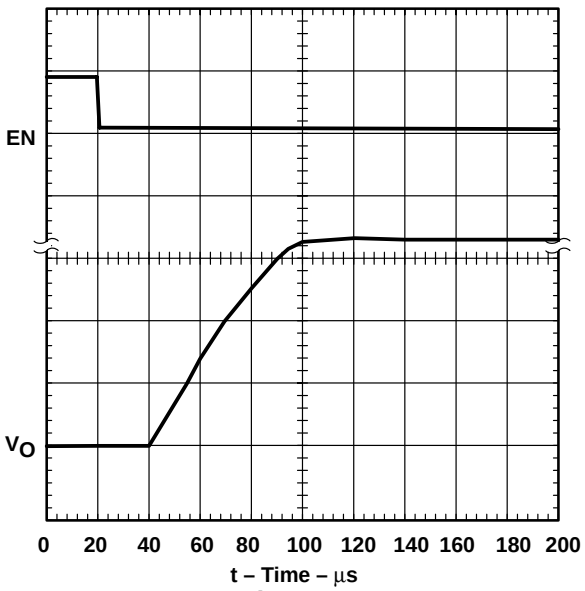


Figure 12

TYPICAL CHARACTERISTICS

TPS77015
LINE TRANSIENT RESPONSE

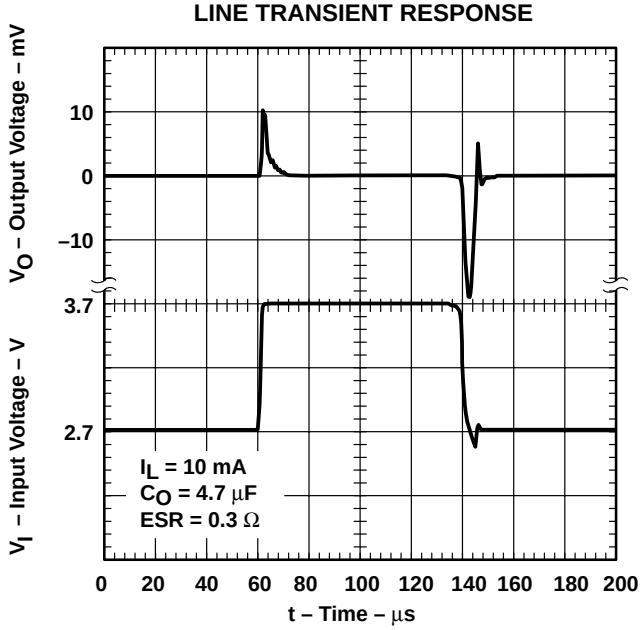


Figure 13

TPS77015
LOAD TRANSIENT RESPONSE

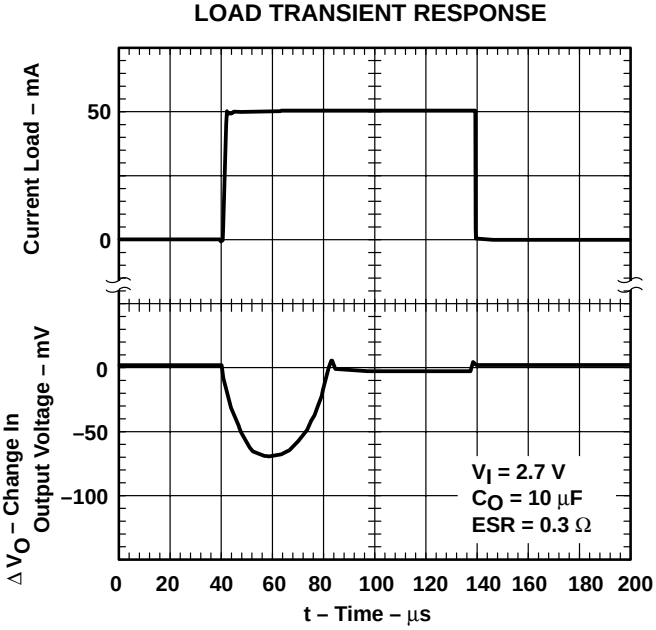


Figure 14

TPS77033
LINE TRANSIENT RESPONSE

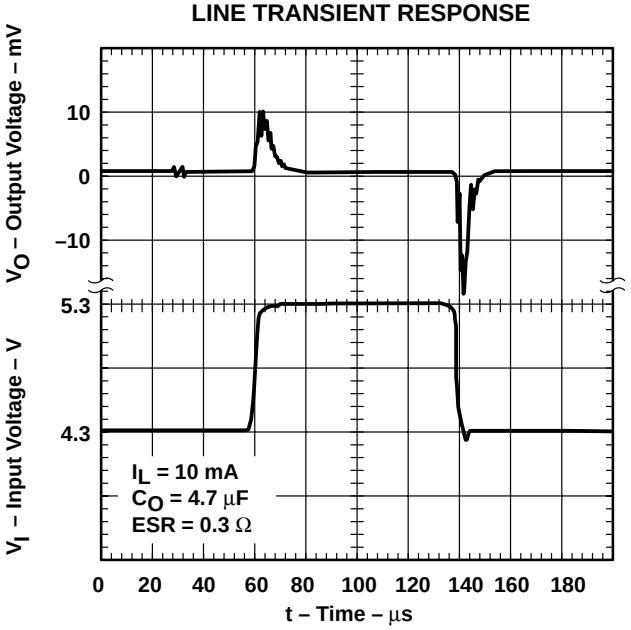


Figure 15

TPS77033
LOAD TRANSIENT RESPONSE

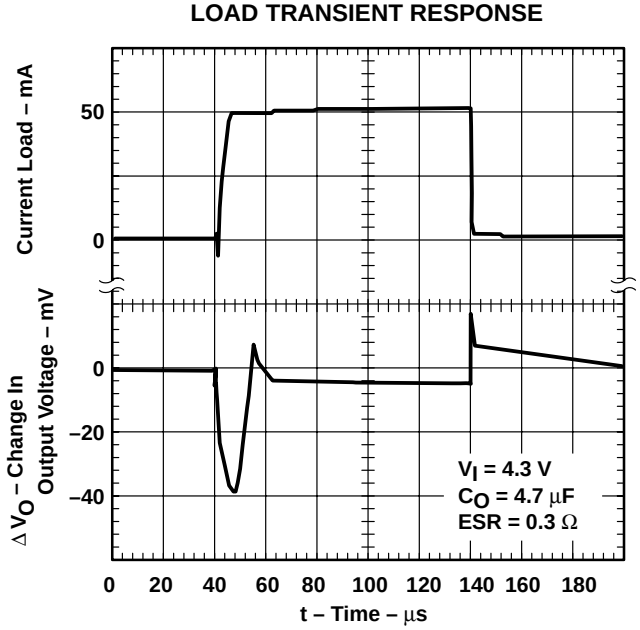


Figure 16

TYPICAL CHARACTERISTICS

TPS77033
TYPICAL REGIONS OF STABILITY
EQUIVALENT SERIES RESISTANCE (ESR)†
vs
OUTPUT CURRENT

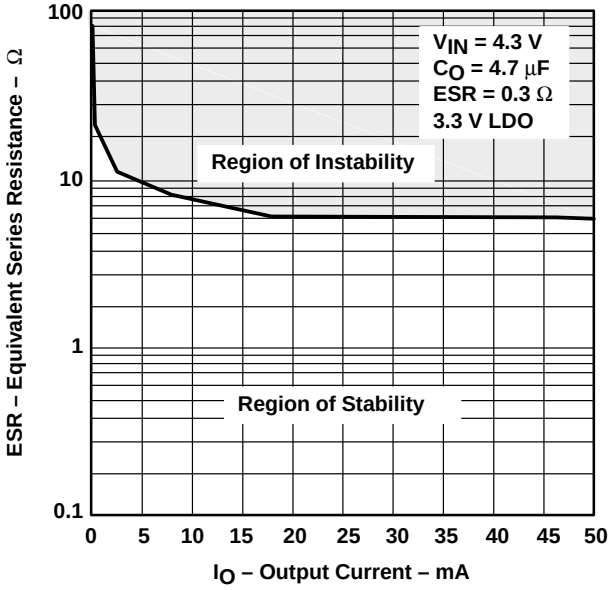


Figure 17

TPS77033
TYPICAL REGIONS OF STABILITY
EQUIVALENT SERIES RESISTANCE (ESR)
vs
ADDED CERAMIC CAPACITANCE

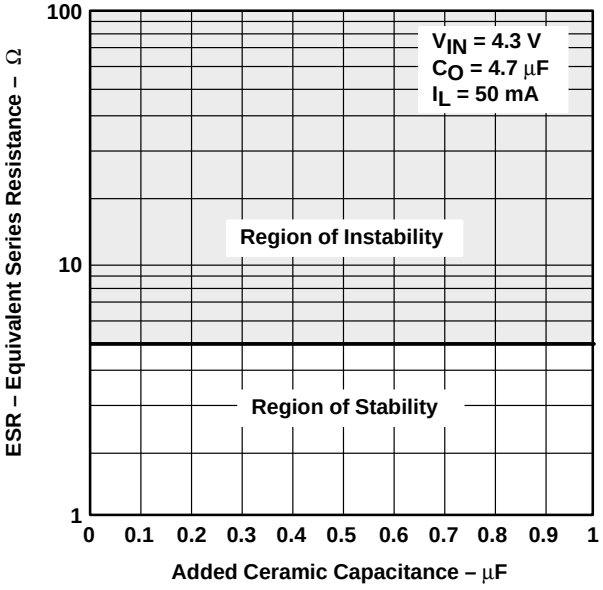


Figure 18

TPS77033
TYPICAL REGIONS OF STABILITY
EQUIVALENT SERIES RESISTANCE (ESR)†
vs
OUTPUT CURRENT

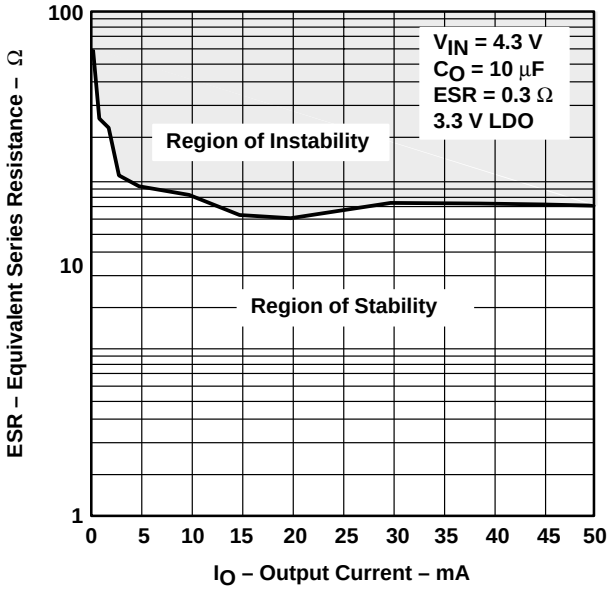


Figure 19

TPS77033
TYPICAL REGIONS OF STABILITY
EQUIVALENT SERIES RESISTANCE (ESR)
vs
ADDED CERAMIC CAPACITANCE

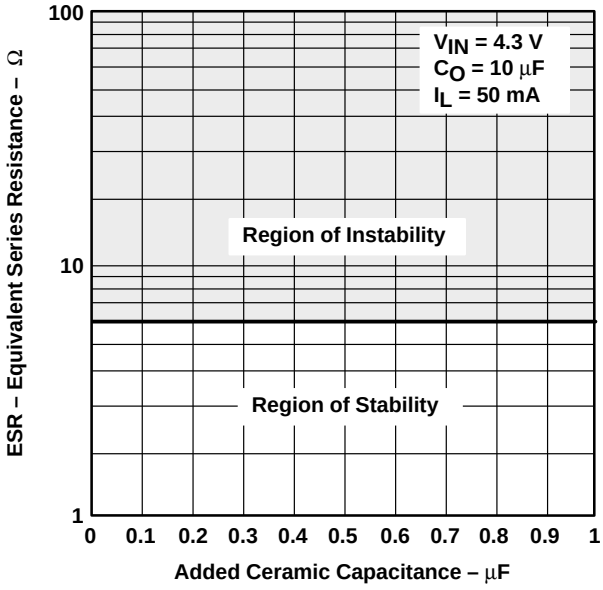


Figure 20

APPLICATION INFORMATION

The TPS770xx family of low-dropout (LDO) regulators have been optimized for use in battery-operated equipment. They feature extremely low dropout voltages, low quiescent current (17 μA nominally), and enable inputs to reduce supply currents to less than 1 μA when the regulators are turned off.

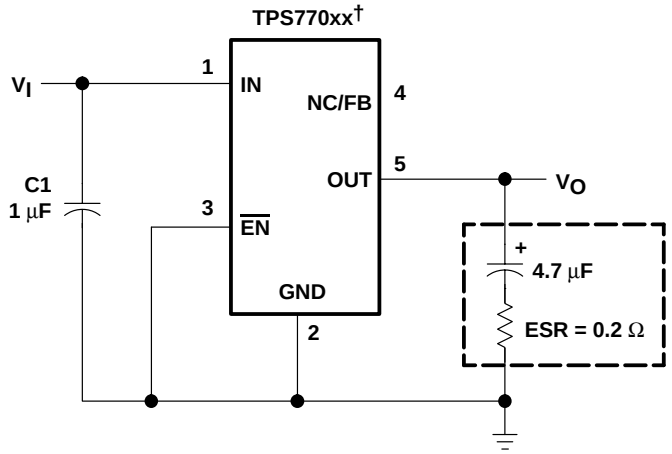
device operation

The TPS770xx uses a PMOS pass element to dramatically reduce both dropout voltage and supply current over more conventional PNP-pass-element LDO designs. The PMOS pass element is a voltage-controlled device and, unlike a PNP transistor, it does not require increased drive current as output current increases. Supply current in the TPS770xx is essentially constant from no load to maximum load.

Current limiting and thermal protection prevent damage by excessive output current and/or power dissipation. The device switches into a constant-current mode at approximately 350 mA; further load reduces the output voltage instead of increasing the output current. The thermal protection shuts the regulator off if the junction temperature rises above approximately 165°C. Recovery is automatic when the junction temperature drops approximately 25°C below the high temperature trip point. The PMOS pass element includes a back gate diode that conducts reverse current when the input voltage level drops below the output voltage level.

A voltage of 1.7 V or greater on the EN input will disable the TPS770xx internal circuitry, reducing the supply current to 1μA. A voltage of less than 0.9 V on the $\overline{EN}$ input will enable the TPS770xx and will enable normal operation to resume. The $\overline{EN}$ input does not include any deliberate hysteresis, and it exhibits an actual switching threshold of approximately 1.5 V.

A typical application circuit is shown in Figure 21.



† TPS77012, TPS77015, TPS77018, TPS77025, TPS77027, TPS77028, TPS77030, TPS77033, TPS77050 (fixed-voltage options).

Figure 21. Typical Application Circuit

APPLICATION INFORMATION

external capacitor requirements

Although not required, a 0.047-μF or larger ceramic input bypass capacitor, connected between IN and GND and located close to the TPS770xx, is recommended to improve transient response and noise rejection. A higher-value electrolytic input capacitor may be necessary if large, fast-rise-time load transients are anticipated and the device is located several inches from the power source.

Like all low dropout regulators, the TPS770xx requires an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance is 4.7 μF. The ESR (equivalent series resistance) of the capacitor should be between 0.2 Ω and 10 Ω. to ensure stability. Capacitor values larger than 4.7 μF are acceptable, and allow the use of smaller ESR values. Capacitances less than 4.7 μF are not recommended because they require careful selection of ESR to ensure stability. Solid tantalum electrolytic, aluminum electrolytic, and multilayer ceramic capacitors are all suitable, provided they meet the requirements described above. Most of the commercially available 4.7 μF surface-mount solid tantalum capacitors, including devices from Sprague, Kemet, and Nichico, meet the ESR requirements stated above. Multilayer ceramic capacitors may have very small equivalent series resistances and may thus require the addition of a low value series resistor to ensure stability.

CAPACITOR SELECTION

PART NO.	MFR.	VALUE	MAX ESR†	SIZE (H × L × W)†
T494B475K016AS	KEMET	4.7 μF	1.5 Ω	1.9 × 3.5 × 2.8
195D106x0016x2T	SPRAGUE	10 μF	1.5 Ω	1.3 × 7.0 × 2.7
695D106x003562T	SPRAGUE	10 μF	1.3 Ω	2.5 × 7.6 × 2.5
TPSC475K035R0600	AVX	4.7 μF	0.6 Ω	2.6 × 6.0 × 3.2

† Size is in mm. ESR is maximum resistance in Ohms at 100 kHz and T_A = 25°C. Contact manufacturer for minimum ESR values.

APPLICATION INFORMATION

output voltage programming

The output voltage of the TPS77001 adjustable regulator is programmed using an external resistor divider as shown in Figure 22. The output voltage is calculated using:

$$V_O = V_{ref} \times \left(1 + \frac{R1}{R2}\right) \quad (1)$$

where

V_{ref} = 1.224 V typ (the internal reference voltage)

Resistors R1 and R2 should be chosen for approximately 7-μA divider current. Lower value resistors can be used but offer no inherent advantage and waste more power. Higher values should be avoided as leakage currents at FB increase the output voltage error. The recommended design procedure is to choose R2 = 169 kΩ to set the divider current at 7 μA and then calculate R1 using:

$$R1 = \left(\frac{V_O}{V_{ref}} - 1\right) \times R2 \quad (2)$$

OUTPUT VOLTAGE PROGRAMMING GUIDE

OUTPUT VOLTAGE (V)	DIVIDER RESISTANCE (kΩ)‡	
	R1	R2
2.5	174	169
3.3	287	169
3.6	324	169
4.0	383	169
5.0	523	169

‡ 1% values shown.

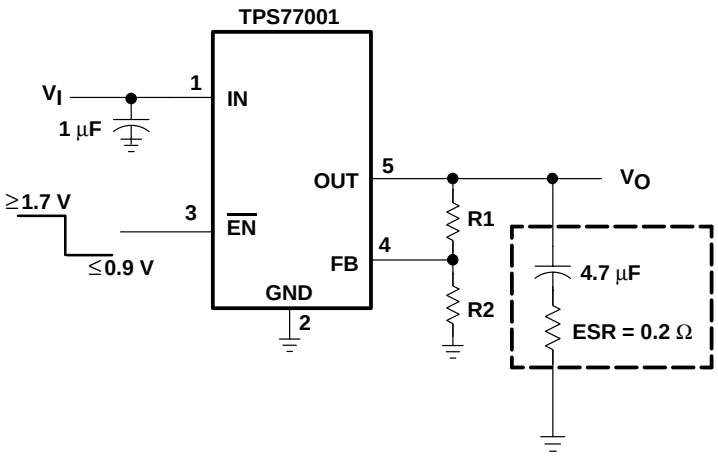


Figure 22. TPS77001 Adjustable LDO Regulator Programming

APPLICATION INFORMATION

power dissipation and junction temperature

Specified regulator operation is assured to a junction temperature of 125°C; the maximum junction temperature should be restricted to 125°C under normal operating conditions. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation, $P_{D(max)}$, and the actual dissipation, P_D, which must be less than or equal to $P_{D(max)}$.

The maximum-power-dissipation limit is determined using the following equation:

$$P_{D(max)} = \frac{T_J max - T_A}{R_{\theta JA}}$$

Where:

$T_J max$ is the maximum allowable junction temperature

$R_{\theta JA}$ is the thermal resistance junction-to-ambient for the package, see the dissipation rating table.

T_A is the ambient temperature.

The regulator dissipation is calculated using:

$$P_D = \left(V_I - V_O\right) \times I_O$$

Power dissipation resulting from quiescent current is negligible. Excessive power dissipation will trigger the thermal protection circuit.

regulator protection

The TPS770xx PMOS-pass transistor has a built-in back diode that conducts reverse current when the input voltage drops below the output voltage (e.g., during power down). Current is conducted from the output to the input and is not internally limited. If extended reverse voltage operation is anticipated, external limiting might be appropriate.

The TPS770xx features internal current limiting and thermal protection. During normal operation, the TPS770xx limits output current to approximately 350 mA. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds approximately 165°C, thermal-protection circuitry shuts it down. Once the device has cooled down to below approximately 140°C, regulator operation resumes.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS77001DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCPI	Samples
TPS77001DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCPI	Samples
TPS77012DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCQI	Samples
TPS77012DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCQI	Samples
TPS77015DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCRI	Samples
TPS77015DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCRI	Samples
TPS77018DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCSI	Samples
TPS77018DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCSI	Samples
TPS77018DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCSI	Samples
TPS77025DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCTI	Samples
TPS77025DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCTI	Samples
TPS77025DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCTI	Samples
TPS77027DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCUI	Samples
TPS77027DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCUI	Samples
TPS77028DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCVI	Samples
TPS77028DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCVI	Samples
TPS77030DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCWI	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS77030DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCWI	Samples
TPS77030DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCWI	Samples
TPS77030DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCWI	Samples
TPS77033DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	PCXI	Samples
TPS77033DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	PCXI	Samples
TPS77033DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	PCXI	Samples
TPS77033DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	PCXI	Samples
TPS77050DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCYI	Samples
TPS77050DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCYI	Samples
TPS77050DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PCYI	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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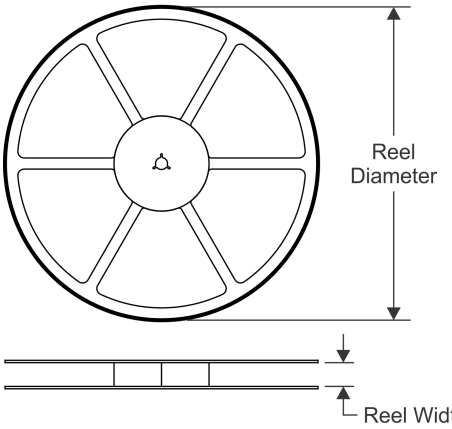
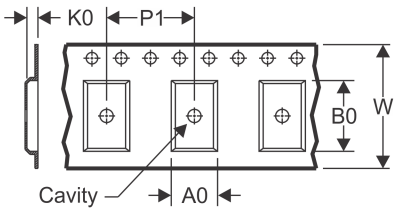
TAPE AND REEL INFORMATION

REEL DIMENSIONS

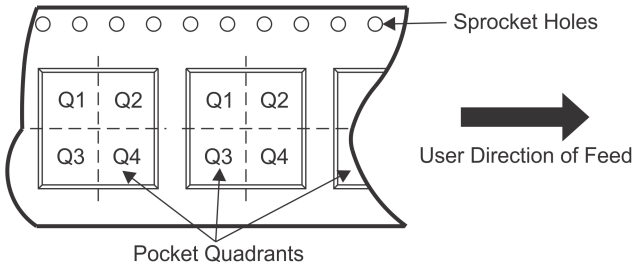


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

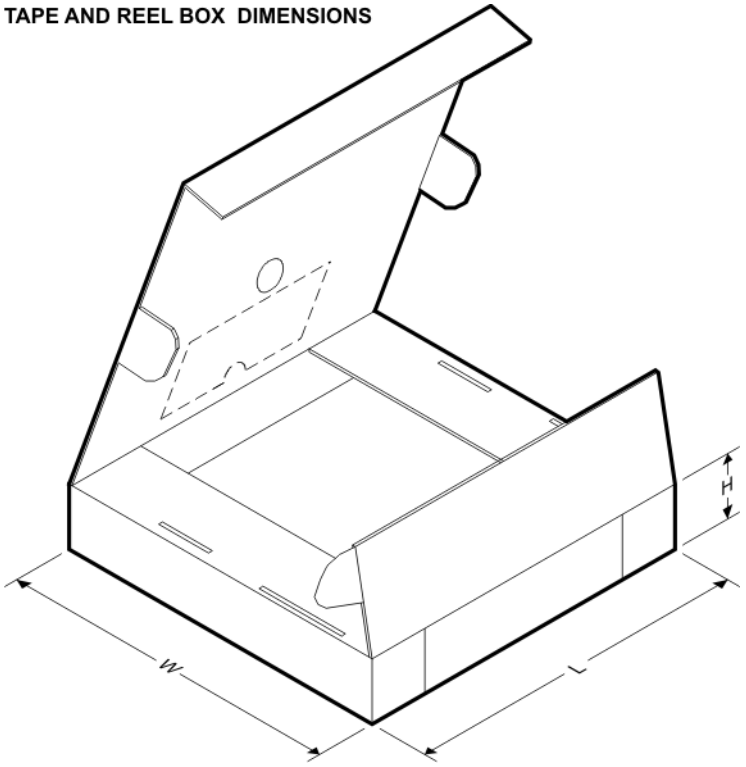


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS77001DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS77001DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS77012DBVR	SOT-23	DBV	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS77012DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS77012DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS77012DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS77015DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS77015DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS77018DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS77018DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS77025DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS77025DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS77025DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS77025DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS77027DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS77027DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS77028DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS77028DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS77030DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS77030DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS77033DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS77033DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS77050DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
TPS77050DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS77001DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS77001DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS77012DBVR	SOT-23	DBV	5	3000	203.0	203.0	35.0
TPS77012DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS77012DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS77012DBVT	SOT-23	DBV	5	250	203.0	203.0	35.0
TPS77015DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS77015DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS77018DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS77018DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS77025DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0

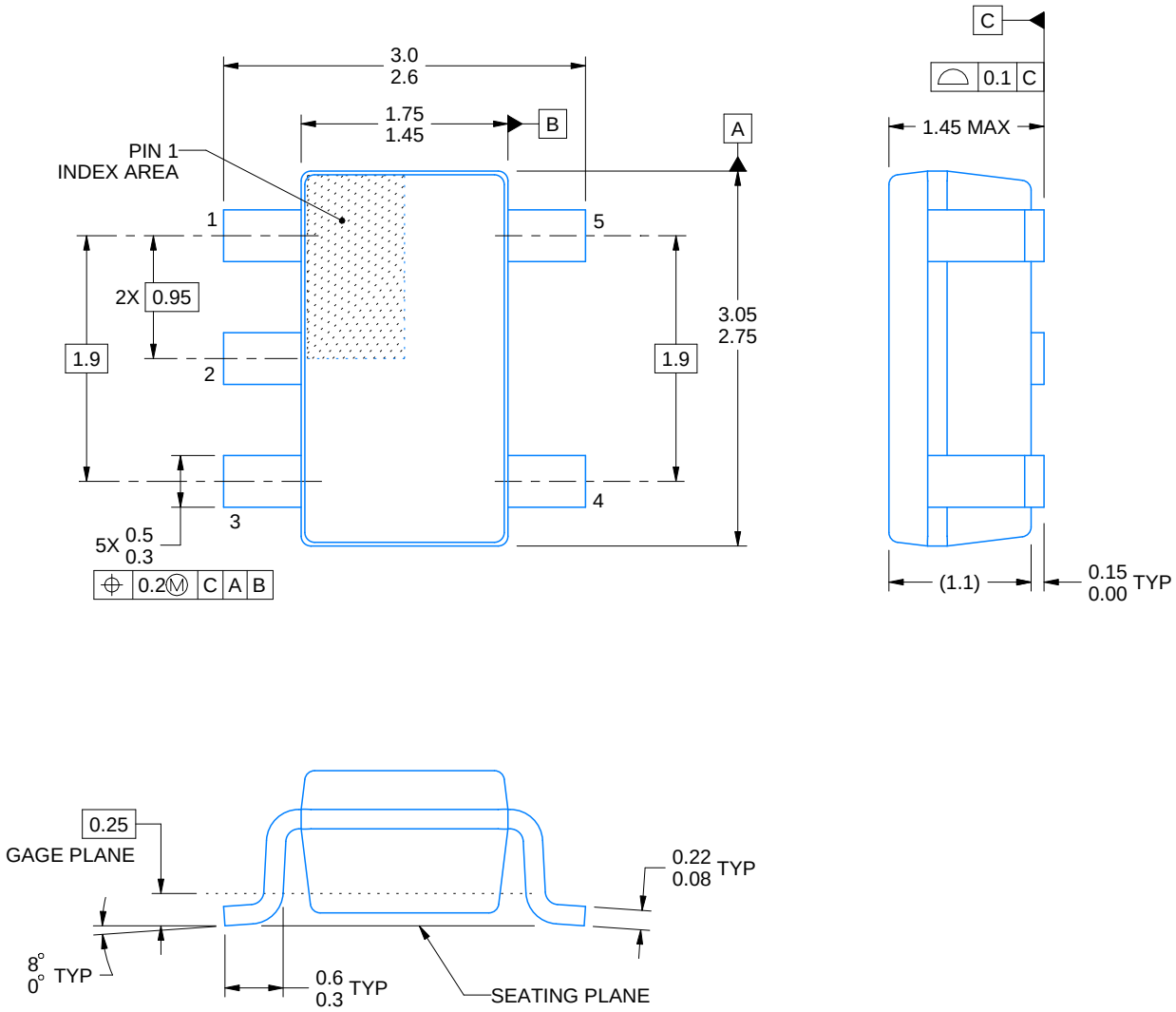
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS77025DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS77025DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS77025DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS77027DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS77027DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS77028DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS77028DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS77030DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS77030DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS77033DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS77033DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS77050DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS77050DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0

PACKAGE OUTLINE

DBV0005A

SOT-23 - 1.45 mm max height

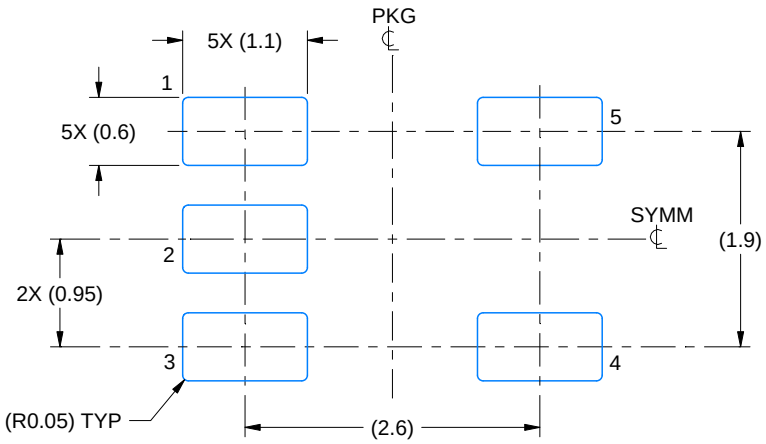
SMALL OUTLINE TRANSISTOR



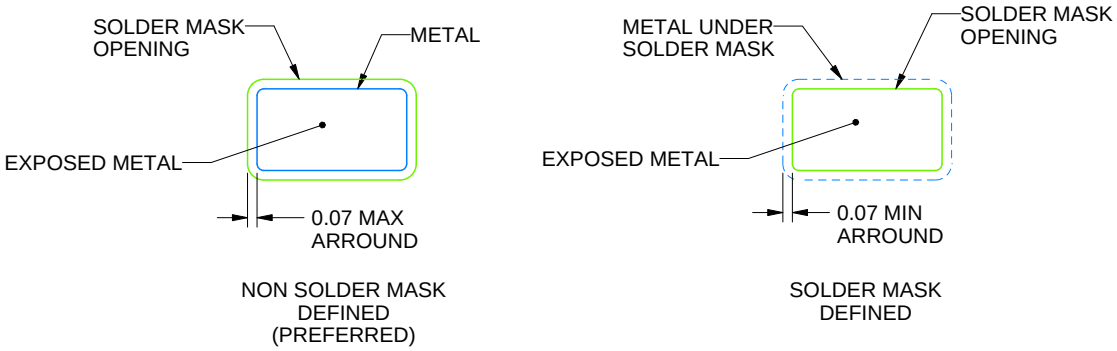
4214839/D 11/2018

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Refernce JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

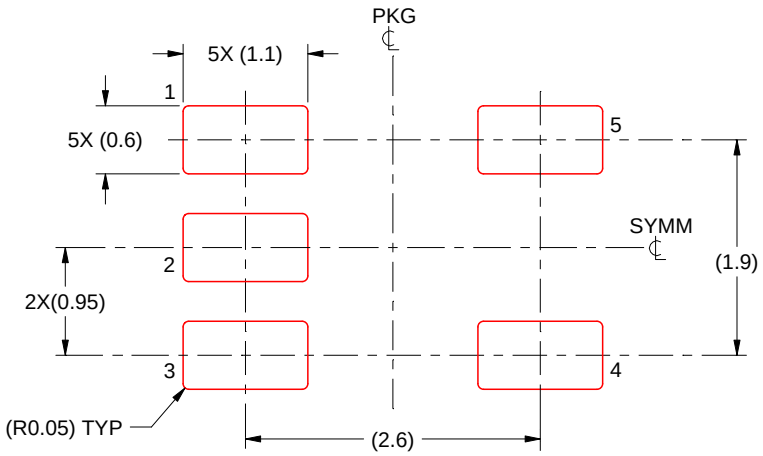


SOLDER MASK DETAILS

4214839/D 11/2018

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/D 11/2018

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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